

"Phase Transformation in Materials"

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- **Binary System** mixture/ solution / compound
- Gibbs Free Energy in Binary System

$$G_1 = X_A G_A + X_B G_B \quad J/mol$$
 $G_2 = G_1 + \Delta G_{mix} \quad J/mol$

Ideal solution $(\Delta H_{mix} = 0)$ $\Delta G^{mix} = RT(X_A \ln X_A + X_B \ln X_B)$

$$G = X_A G_A + X_B G_B + RT(X_A \ln X_A + X_B \ln X_B)$$

Regular solution $\Delta H_{mix} = P_{AB}\varepsilon \text{ where } \varepsilon = \varepsilon_{AB} - \frac{1}{2}(\varepsilon_{AA} + \varepsilon_{BB})$ $G = X_A G_A + X_B G_B + \Omega X_A X_B + RT(X_A \ln X_A + X_B \ln X_B)$

- Chemical potential and Activity

$$\mu_{A} = \left(\frac{\partial G'}{\partial n_{A}}\right)_{T, P, n}$$

•
$$\mu_A = G_A + RT \ln a_A$$

$$\ln\!\left(\frac{a_A}{X_A}\right) = \frac{\Omega}{RT}(1 - X_A)^2$$

 $\frac{a_A}{X_A} = \gamma_A = \text{activity coefficient}$

 μ 는 조성에 의해 결정되기 때문에 dn_A 가 매우 작아서 조성변화 없어야

- Binary System mixture/ solution / compound Ideal solution ($\Delta H_{mix} = 0$) Random distribution

Regular solution $\Delta H_{mix} = P_{AB} \varepsilon$ where $\varepsilon = \varepsilon_{AB} - \frac{1}{2} (\varepsilon_{AA} + \varepsilon_{BB})$ $\varepsilon \approx 0$

$$\Delta H_{mix} > 0 \text{ or } \Delta H_{mix} < 0$$

Real solution



Ordered structure



(a) $\varepsilon < 0$, $\Delta H_{mix} < 0$ Fig. 1.8 Ordered alloys $P_{AB} \uparrow \longrightarrow \text{Internal E} \qquad P_{AA}, P_{BB} \uparrow$

(b) $\varepsilon > 0$, $\Delta H_{mix} > 0$ Clustering



(c) when the size difference is large strain effect Interstitial solution

Q9: Ordered phase II: "Long range order (LRO)"

(1)superlattice, 2)intermediate phase, 3)intermetallic compound)





diate phases: (a) for an intermetallic com-(b) for an intermediate phase with a wide



* Compound : AB, A₂B...
→ entropy↓
→ covalent, ionic contribution.
→ enthalpy more negative ↓

 $\Delta H_{mix}^{S} << 0$

Small composition range → G ↓



Fig. 1.23 Free energy curves for intermed pound with a very narrow stability range, (stability range.



Superlattice formation: order-disorder transformation

- ϵ < 0, ΔH_{mix} < 0
- between dissimilar atoms than between similar atoms
- Large electrochemical factor: tendency for the solute atoms to avoid each other and to associate with the solvent atoms
- Size factor just within the favorable limit: lead to atomic rearrangement

so as to relieve the lattice distortion imposed by the solute atoms



 β brass superlattice viewed as two inter-penetrating cubic lattices

 $\Delta G_{mix} = \Delta H_{mix} - T\Delta S_{mix} \quad \text{Ordered phase}$

$$\epsilon$$
 < 0, Δ H_{mix}< 0

7

Fig. 1.21 Part of the Cu-Au phase diagram showing the regions where the Cu₂Au and CuAu superlattices are stable.



- The entropy of mixing of structure with LRO is extremely small and the degree • of order decrease with increasing temperature until above some critical temperature there is no LRO at all.
- This temperature is a maximum when the composition is the ideal required • for the superlattice.
- The critical temperature for loss of LRO increases with increasing Ω or ΔH_{mix} • and in many systems the ordered phase is stable up to the melting point.

Order-disorder phase transformation

- Not classical phase change=<u>~not depend on diffusion process</u>
- change of temperature allowed a continuous re-arrangement of atoms without changing the phase = "2nd order transition"
- boundary: ordered lattice & disordered lattice/phase rule could not applied there are cases in which an ordered phase of one composition exists in equilibrium with a disordered phase of a different composition.
- Simple composition of the type AB or AB₃ can the transformation

(i.e. at the temperature maximum) be considered diffusionless.



Ordered Phase





 $\epsilon < 0, \Delta H_{mix} < 0$





Intermediate Phase

 ϵ < 0, Δ H_{mix}< 0 / Δ H_{mix}~ -38 kJ/mol



11

Intermediate Phase

 $\epsilon << 0$, $\Delta H_{mix} << 0 / \Delta H_{mix} \sim -142 \text{ kJ/mol}$



12

1.3 Binary Solutions

Intermediate Phase

_"different crystal structure as either of the pure component"

3 main factors

determining the structure of Intermediate phase ?

1) Relative atomic size

- Laves phase (size difference: 1.1~1.6 ex: MgCu₂) fill space most efficiently ~ stable
- Interstitial compound: MX, M₂X, MX₂, M₆X

M= Cubic or HCP ex: Zr, Ti, V, Cr, etc, X= H, B, C, and N

2) Relative valency electron

- electron phases $ex_{\alpha} \& \beta$ brass # of valency electrons per unit cell \rightarrow <u>depending on compositional change</u>

3) Electronegativity

- <u>very different electronegativites</u> → ionic bond_normal valency compounds ex Mg₂Sn



MgCu₂ (A Laves phase)



Q1: "Clustering"? → Phase separation Metastable vs Stable miscibility gap * The degree of ordering or clustering will decrease as temp. increases due to the increasing importance of entropy.





$\epsilon > 0$, $\Delta H_{mix} > 0 / \Delta H_{mix} \sim +26 \text{ kJ/mol}$



Cooling process in the miscibility gap



18

Dendrite / interdendrite formation

Compositional analysis of as-cast CoCrFeNi/Cu HEA (dendrite)



- ROI 1, 2 : 1.4 nm x 2 nm x 2 nm
- ROI 3 : 1.2 nm x 2 nm x 23 nm

(1D concentration profile)

1	at%	2	at%
Со	26.19	Со	0.33
Cr	24.15	Cr	0.46
Fe	24.59	Fe	0.39
Ni	19.59	Ni	5.00
Cu	4.74	Cu	93.56
3-1'	at%	3-2'	at%
3-1' Co	at% 25.29	3-2' Co	at% 2.01
3-1' Co Cr	at% 25.29 25.63	3-2' Co Cr	at% 2.01 3.35
3-1' Co Cr Fe	at% 25.29 25.63 23.63	3-2' Co Cr Fe	at% 2.01 3.35 2.56
3-1' Co Cr Fe Ni	at% 25.29 25.63 23.63 20.66	3-2' Co Cr Fe Ni	at% 2.01 3.35 2.56 6.90

- Dendrite region: matrix (4.74 at%Cu) + 2nd phase (93.56 at%Cu)
- No segregation at the interface between Matrix and 2nd phase

$\epsilon > 0$, $\Delta H_{mix} > 0 / \Delta H_{mix} \sim +17 \text{ kJ/mol}$





$\epsilon > 0$, $\Delta H_{mix} > 0 / \Delta H_{mix} \sim +5 \text{ kJ/mol}$





$\epsilon >> 0$, $\Delta H_{mix} >> 0 / \Delta H_{mix} \sim +60 \text{ kJ/mol}$





$\epsilon >> 0$, $\Delta H_{mix} >> 0 / \Delta H_{mix} \sim +58 \text{ kJ/mol}$



Positive heat of mixing relation among constituent elements



Nucleation and growth ↔ Spinodal decomposition without any barrier to the nucleation process

* Ti-Y-Al-Co system





 $(Y_{56}Al_{24}Co_{20})_{25}(Ti_{56}Al_{24}Co_{20})_{75}$

 $(Y_{56}Al_{24}Co_{20})_{50}(Ti_{56}Al_{24}Co_{20})_{50}$

 $(Y_{56}Al_{24}Co_{20})_{65}(Ti_{56}Al_{24}Co_{20})_{35}$



FIGURE 5.17

Schematic of the miscibility gap and the sequence of phase formation during cooling in the La–Zr–Al–Cu–Ni system. The positions of letters (a) to (d) in the diagram on the left correspond to the schematic microstructures (a) to (d) on the right. (Reprinted from Kündig, A.A. et al., *Acta Mater.*, 52, 2441, 2004. With permission.)



Phase separation in metallic glasses



- Binary System mixture/ solution / compound Ideal solution ($\Delta H_{mix} = 0$) Random distribution

Regular solution $\Delta H_{mix} = P_{AB} \varepsilon$ where $\varepsilon = \varepsilon_{AB} - \frac{1}{2} (\varepsilon_{AA} + \varepsilon_{BB})$ $\varepsilon \approx 0$

$$\int \Delta H_{mix} > 0 \text{ or } \Delta H_{mix} < 0$$

Real solution



Ordered structure



Fig. 1.8 (a) $\varepsilon < 0$, $\Delta H_{mix} < 0$ Ordered alloys $P_{AB} \uparrow \longrightarrow \text{Internal E} \qquad P_{AA}, P_{BB} \uparrow$

(b) $\varepsilon > 0$, $\Delta H_{mix} > 0$ Clustering



(c) when the size difference is large strain effect Interstitial solution



Q2: How can we define equilibrium in heterogeneous systems?

1.4

 $G = X_A G_A + X_B G_B$

Equilibrium in Heterogeneous Systems

A, B different crystal structure \rightarrow two free energy curves must be drawn, one for each structure.

We have dealt with the case where the components A and B have the same crystal structure. What would happen when the components A and B have a different crystal structure? → heterogeneous system





Fig. 1.26 The molar free energy of a two-phase mixture (α + β)

Lever rule



₩_ =

1.4

Equilibrium in Heterogeneous Systems



Variation of activity with composition

The most stable state, with the lowest free energy, is usually defined as the state in which the pure component has unit activity of A in pure α .

when
$$X_A = 1 \rightarrow a_A^{\alpha} = 1$$

when $X_B = 1 \rightarrow a_B^{\beta} = 1$

when α and β in equil.

$$\mathbf{a}_{\mathsf{A}}^{\alpha} = \mathbf{a}_{\mathsf{A}}^{\beta}$$

 $\mathbf{a}_{\mathsf{B}}^{\alpha} = \mathbf{a}_{\mathsf{B}}^{\beta}$



Unified activity of two phase

Fig. 1.28 The variation of a_A and a_B with composition for a binary system containing two ideal solutions, α and β 35

Equilibrium in Heterogeneous Systems




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 or $\Delta H_{mix} < 0$

Real solution



Ordered structure



(a) $\varepsilon < 0$, $\Delta H_{mix} < 0$ Ordered alloys $P_{AB} \uparrow \longrightarrow \text{Internal E} \qquad P_{AA}, P_{BB} \uparrow$

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Equilibrium in Heterogeneous Systems



Contents for today's class

1.5 Binary phase diagrams_Variation of the simple phase diagram

complete solid solution → eutectic/peritectic system

• Gibbs Phase Rule F = C - P + 1 (constant pressure)

1.5.7

1.5.6

Effect of Temperature on Solid Solubility

1.5.8

- Equilibrium Vacancy Concentration
- **1.6 Influence of Interfaces on Equilibrium**
- **1.8** Additional thermodynamic relationships for binary solutions
- Gibbs-Duhem Equation: Be able to calculate the change in

chemical potential that result from a change in alloy composition.

Q1: How equilibrium is affected by temperature in complete solid solution?

1) A Simple Phase Diagram



1) A Simple Phase Diagram



Fig. Free energy curves for liquid and solid phases in the U-Zr system at 1500°, 1800° and 2000 °K.

1) A Simple Phase Diagram

- 1) Variation of temp.: G^L > G^s
- 2) Decrease of curvature of G curve
 - (∵ decrease of -T∆S_{mix} effect)

Assumption:

(1) completely miscible in solid and liquid.

9

(2) Both are ideal soln.

(3)
$$T_m(A) > T_m(B)$$

(4)
$$T_1 > T_m(A) > T_2 > T_m(B) > T_3$$



1) A Simple Phase Diagram

The simplest type of binary phase diagrams is the isomorphous system, in which the two constituents form a continuous solid solution over the entire composition range. An example is the Ni-Cu system.

Solidification of alloy C_0 starts on cooing at T₁. The first solid formed has a composition of C_{s1} and the liquid C_0 . On further cooling the solid particles grow larger in size and change their composition to C_{s2} and then C_0 , following the solidus whereas the liquid decrease in volume and changes its composition from C_0 to C_{L3} following the liquidus. The solidification completes at T₃.



Cooling Curves determination of Phase diagrams



Q4: How equilibrium is affected by temperature in systems with miscibility gap?



How to characterize G^s mathematically in the region of miscibility gap between e and f?



2) Systems with miscibility gab $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} > 0$

- When A and B atoms dislike each other, $\Delta H_{mix} > 0$
- In this case, the free energy curve at low temperature has a region of negative curvature, $\frac{d^2G}{dX_n^2} < 0$
- This results in a 'miscibility gap' of α ' and α " in the phase diagram



15

* Variant of the simple phase diagram



Fig. Derivation of the phase diagram (Fig. 29b) from free energy curves for the liquid and solid phases. $T_A > T_B > T_1 > T_2 > T_3$.

3) Ordered alloys_Variation of the simple phase diagram

 $\Delta H_{mix} < 0$





Fig. Phase diagram with a maximum in the liquidus.

congruent maxima



Fig. Appearance of an ordered α' phase at low temperatures.

Q2: How equilibrium is affected by temperature in simple eutectic/peritectic systems?

- 1.5 Binary phase diagrams
 - **4) a. Simple Eutectic Systems** $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} >> 0$
- ΔH_m>>0 and the miscibility gap extends to the melting temperature.
 (when both solids have the same crystal structure.)



Fig. 1.32 The derivation of a eutectic phase diagram where both solid phases have the same crystal structure.

(when each solid has the different crystal structure.)



²⁰

Fig. 1.32 The derivation of a eutectic phase diagram where each solid phases has a different crystal structure.

4) b. Simple Peritectic Systems



Peritectic reaction

Considerable difference between the melting points



Fig. 61. Effect of increasingly positive departure from ideality in changing the phase diagram from a continuous series of solutions to a peritectic-type.



Fig. 43. Effect of increasingly positive departure from ideality in changing the phase diagram for a continuous series of solutions to a eutectic-type.

Peritectic reaction (when both solids have the same crystal structure.)



Fig. 62. Derivation of the peritectic phase diagram from the free energy curves for the liquid and solid phases.

Peritectic reaction (when both solids have the different crystal structure.)



24

Fig. 1.33 Free energy curves resulting in a peritectic phase diagram. T2 is the peritectic temperature.

Cu-Zn Phase Diagram

Eutectoid and Peritectic Reactions



Eutectoid: one solid phase transforms into two other solid phases upon cooling

<u>Peritectic</u>: one solid and one liquid phase transform into another solid phase upon cooling

<u>Peritectoid</u>: two other solid phases transform into another solid phase upon cooling



5) Phase diagrams containing intermediate phases



Fig. 1.34 The derivation of a complex phase diagram.

5) Phase diagrams containing intermediate phases



Fig. 1.35 Free energy diagram to illustrate that the range of compositions over which a phase is stable depends on the free energies of the other phases in equilibrium.

θ phase in the Cu-Al system is usually denoted as CuAl₂ although the composition X_{Cu}=1/3, X_{Al}=2/3 is not covered by the θ field on the phase diagram.



X.L. Liu, I. Ohnuma, R. Kainuma, and K. Ishida, J. Alloys Compds, 264, 201-208 (1998)

Summary I: Binary phase diagrams

1) Simple Phase Diagrams

Both are ideal soln. \rightarrow 1) Variation of temp.: $G^L > G^s$ 2) Decrease of curvature of G curve (\because decrease of $-T\Delta S_{mix}$ effect)

2) Systems with miscibility gap $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} > 0$

1)Variation of temp.: $G^{L} > G^{s}$ 2)Decrease of curvature of G curve + Shape change of G curve by H

3) Ordered Alloys $\Delta H_{mix}^{L} = 0$ $\Delta H_{mix}^{S} < 0$ $\Delta H_{mix} < 0 \rightarrow A$ atoms and B atoms like each other. \rightarrow Ordered alloy at low T $\Delta H_{mix} << 0 \rightarrow$ The ordered state can extend to the melting temperature.

4) a. Simple Eutectic Systems $\Delta H_{mix}^{L} = 0$

$$A_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} >> 0$$

 \rightarrow miscibility gap extends to the melting temperature.

Simple Peritectic Systems

→ Considerable difference between the melting points

5) Phase diagrams containing intermediate phases

Stable composition + Minimum G with stoichiometric composition

Summary I: Binary phase diagrams

- Equilibrium in Heterogeneous Systems

 $G_0^{\beta} > G_0^{\alpha} > G_0^{\alpha+\beta} \implies \alpha + \beta$ separation \implies unified chemical potential



Eutectic reaction



Fig. 43. Effect of increasingly positive departure from ideality in changing the phase diagram for a continuous series of solutions to a eutectic-type.



Fig. 61. Effect of increasingly positive departure from ideality in changing the phase diagram from a continuous 31 series of solutions to a peritectic-type.

Q3: "Gibbs Phase Rule"?

Gibbs' Phase Rule allows us to construct phase diagram to represent and interpret phase equilibria in heterogeneous geologic systems.

F = C - P + 1 (constant pressure)

The Gibbs Phase Rule

Degree of freedom (number of variables that can be varied independently)

= the number of variables – the number of constraints

- Number of phases : p, number of components : c,
- # of controllable variable : composition (c-1)p, temperature : p, pressure : p
- # of restrictions :

(p-1)c from chemical equilibrium

p-1 from thermal equilibrium

p-1 from mechanical equilibrium

$$\mu_i^a = \mu_i^\beta = \mu_i^\gamma = \dots = \mu_i^p$$
$$T^a = T^\beta = T^\gamma = \dots = T^p$$

$$P^a = P^{\beta} = P^{\gamma} = \dots = P^p$$

- Number of variable can be controlled with maintaining equilibrium f = (c-1)p + p + p - (p-1)c - (p-1) - (p-1) = c - p + 2 f = c - p + 2(1.49)

- If pressure is constant : f = (c-1)p + p - (p-1)c - (p-1) = c - p + 1 (1.50) 33

The Gibbs Phase Rule

In chemistry, Gibbs' phase rule describes the possible number of degrees of freedom (F) in a closed system at equilibrium, in terms of the number of separate phases (P) and the number of chemical components (C) in the system. It was deduced from thermodynamic principles by Josiah Willard Gibbs in the 1870s.

Gibbs phase rule F =C+N-P

F: degree of freedom C: number of chemical variables N: number of non-chemical variables P: number of phases

In general, Gibbs' rule then follows, as:

F = C - P + 2 (from T, P). (1.49)

From Wikipedia, the free encyclopedia



= 2 - 1 + 1can vary T and composition independently two phase $F = \dot{C} - P + 1$ = 2 - 2 + 1can vary T or composition eutectic point F = C - P + 1= 2 - 3 + 1

can't vary T or composition

The Gibbs Phase Rule

Application of Gibbs phase rule: For a binary system at ambient pressure: C=2 (2 elements) N=1 (temperature, no pressure) For single phase: F=2: % and T (a region) For a 2-phase equilibrium: F=1: % or T (a line) For a 3-phase equilibrium: F=0, (invariant point)



Pb
Q4: "Effect of Temperature on Solid Solubility"?

$$X_B^e = A \exp\left\{-\frac{Q}{RT}\right\}$$
 a) $T \uparrow \implies X_B^e \uparrow$ **b)** X_B^e can never be equal to zero.

1.5.7 Effect of T on solid solubility



$$\frac{\mu_{B}^{\alpha} = {}^{o}G_{B}^{\alpha} + \Omega(1 - X_{B})^{2} + RT \ln X_{B} = \mu_{B}^{\beta} \simeq {}^{o}G_{B}^{\beta}}{\Delta G_{B}^{\beta \to \alpha} = {}^{0}G_{B}^{\alpha} - {}^{o}G_{B}^{\beta} = {}^{o}G_{B}^{\alpha} - \mu_{B}^{\beta} = {}^{o}G_{B}^{\alpha} - \mu_{B}^{\alpha}}{{}^{o}G_{B}^{\alpha} - \mu_{B}^{\alpha}} = -\Omega(1 - X_{B})^{2} - RT \ln X_{B}}$$

$$\frac{\Delta G_{B}^{\beta \to \alpha} = -\Omega(1 - X_{B})^{2} - RT \ln X_{B}}{RT \ln X_{B}} = -\Delta G_{B}^{\beta \to \alpha} - \Omega(1 - X_{B})^{2}}$$

$$(here, X_{B}^{e} <<1)$$

$$RT \ln X_{B}^{e} = -\Delta G_{B}^{\beta \to \alpha} - \Omega$$

$$> X_{B}^{e} = \exp(-\frac{\Delta G_{B}^{\beta \to \alpha} + \Omega}{RT})$$

$$\Delta G_{B}^{\beta \to \alpha} = \Delta H_{B}^{\beta \to \alpha} - T\Delta S_{B}^{\beta \to \alpha} \circ] \boxminus \overrightarrow{\Sigma} \overrightarrow{X}$$

$$X_{B}^{e} = \exp(-\frac{\Delta S_{B}^{\beta \to \alpha}}{R}) \exp(-\frac{\Delta H_{B}^{\beta \to \alpha} + \Omega}{RT})$$

$$\frac{\Delta G_{B}^{\beta \to \alpha} = \Delta H_{B}^{\beta \to \alpha} - T\Delta S_{B}^{\beta \to \alpha} \circ] \boxdot \overrightarrow{\Sigma} \overrightarrow{X}$$

$$X_{B}^{e} = \exp(-\frac{\Omega V}{RT})$$

$$\frac{A G_{B}^{\beta \to \alpha} = A \exp\left\{-\frac{\Omega V}{RT}\right\}$$

$$\frac{A G_{B}^{\beta \to \alpha} - A \exp\left\{-\frac{\Omega V}{RT}\right\}$$

$$\frac{A G_{B}^{\beta \to \alpha} - A \exp\left\{-\frac{\Omega V}{RT}\right\}$$

$$\frac{A G_{B}^{\beta \to \alpha} - A \exp\left\{-\frac{\Omega V}{RT}\right\}$$

 $T \uparrow \implies X_{B}^{e} \uparrow$

Q: heat absorbed (enthalpy) when 1 mole of β dissolves in A rich α as a dilute solution.

* Limiting forms of eutectic phase diagram

The solubility of one metal in another may be so low.



Fig. 53. Evolution of the limiting form of a binary eutectic phase diagram.



b) It is interesting to note that, except at absolute zero, X_B^e can never be equal to zero, that is, no two compo -nents are ever completely insoluble in each other.



Fig. 54. Impossible form of a binary eutectic phase diagram.



Q5: "Equilibrium Vacancy Concentration"?



a) 평형에 미치는 공공의 영향

1.5.8. Equilibrium Vacancy Concentration $\Delta G = \Delta H - T \Delta S$

G of the alloy will depend on the concentration of vacancies and X_{v}^{e} will be that which gives the minimum free energy.

1) Vacancies increase the internal energy of crystalline metal due to broken bonds formation. (Here, vacancy-vacancy interactions are ignored.)

$$\Delta H \cong \Delta H_V X_V$$

2) Vacancies increase entropy because they change the **thermal vibration frequency** and also the **configurational entropy**. "Largest contribution"

Small change due to changes in the vibrational frequencies

Total entropy change is thus

$$\Delta S = \Delta S_{v} X_{v} - R\{X_{v} \ln X_{v} + (1 - X_{v}) \ln(1 - X_{v})\}$$

The molar free energy of the crystal containing X_v mol of vacancies

 $G = G_A + \Delta G = G_A + \Delta H_V X_V - T\Delta S_V X_V + RT\{X_V \ln X_V + (1 - X_V) \ln (1 - X_V)\}$

With this information,

estimate the equilibrium vacancy concentration.

Equilibrium concentration X_v^e will be that which gives the minimum free energy.



Q6: "Influence of Interfaces on Equilibrium"?

$$\Delta G = \frac{2\gamma W_m}{r}$$
 Gibbs-Thomson effect

The G curves so far have been based on the molar Gs of infinitely large amounts of material of a perfect single crystal. Surfaces, GBs and interphase interfaces have been ignored.

1.6 Influence of Interfaces on Equilibrium - b) 평형에 미치는 계면의 영향

$$\Delta G = \Delta P \cdot V \implies \Delta G = \frac{2\gamma V_m}{r}$$

Extra pressure ΔP due to curvature of the α/β



Fig. 1.38 The effect of interfacial E on the solubility of small particle

The concept of a pressure difference is very useful <u>for spherical liquid particles</u>, but it is less convenient in solids (often nonspherical shape).

dG =
$$\Delta G_{\gamma} dn = \gamma dA$$
 $\Delta G_{\gamma} = \gamma dA/dn$
Since n=4 $\pi r^3/3V_m$ and A = 4 πr^2 $\Delta G = \frac{2\gamma V_m}{r}$



Fig. 1.39 Transfer of dn mol of β from large to a small particle.

Gibbs-Thomson effect (capillarity effect):

Free energy increase due to interfacial energy

Quite large solubility differences can arise for particles in the range r=1-100 nm. However, for particles visible in the light microscope (r>1um) capillarity effects are very small.



Fig. 1.38 The effect of interfacial energy on the solubility of small particles.



For small values of the exponent,

$$\frac{X_B^{r=r}}{X_B^{r=\infty}} = \exp(\frac{2\mathcal{W}_m}{RTr}) \approx 1 + \frac{2\mathcal{W}_m}{RTr}$$

Ex)
$$\gamma = 200 \text{mJ/m}^2$$
, $V_{\text{m}} = 10^{-5} \text{ m}^3$, $T = 500 \text{K}$
$$\frac{X_r}{X_{\infty}} = 1 + \frac{1}{r(nm)}$$
46

For r=10 nm, solubility~10% increase



Q7: "Gibbs-Duhem Equation"?

: Be able to calculate the change in chemical potential that result from a change in alloy composition.

$$X_A d\mu_A + X_B d\mu_B = 0$$

$$X_{A}X_{B}\frac{d^{2}G}{dX^{2}} = RT\left\{1 + \frac{d\ln\gamma_{A}}{d\ln X_{A}}\right\} = RT\left\{1 + \frac{d\ln\gamma_{B}}{d\ln X_{B}}\right\}$$

합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화(dµ) 를 계산

1.8 Additional Thermodynamic Relationships for Binary Solutions

Gibbs-Duhem equation: Calculate the change in (dµ) that results from a change in (dX)



Additional Thermodynamic Relationships for Binary Solutions

The Gibbs-Duhem Equation 합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화(dµ)를 계산

be able to calculate the change in chemical potential (dµ) that result from a change in alloy composition (dX).

① For a regular solution,

(2)

$$G = X_{A}G_{A} + X_{B}G_{B} + \Omega X_{A}X_{B} + RT(X_{A}\ln X_{A} + X_{B}\ln X_{B})$$

$$\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}} - 2\Omega$$
For a ideal solution, $\Omega = 0$, $\frac{d^{2}G}{dX^{2}} = \frac{RT}{X_{A}X_{B}}$

$$\textcircled{O} \begin{array}{c} \text{Different form} \\ \text{Eq. 1.75} \end{array} \quad \mu_{B} = G_{B} + RT\ln a_{B} = G_{B} + RT\ln \gamma_{B}X_{B}$$

$$\underbrace{\begin{array}{c} \text{Different form} \\ Y_{B} = a_{B}/X_{B} \end{array}}_{Y_{B} = a_{B}/X_{B}} = \frac{RT}{X_{B}} \left\{ 1 + \frac{X_{B}}{\gamma_{B}} \frac{d\gamma_{B}}{dX_{B}} \right\} = \frac{RT}{X_{B}} \left\{ 1 + \frac{d\ln \gamma_{B}}{d\ln X_{B}} \right\}$$
50

$$\frac{d\mu_B}{dX_B} = \frac{RT}{X_B} \left\{ 1 + \frac{X_B}{\gamma_B} \frac{d\gamma_B}{dX_B} \right\} = \frac{RT}{X_B} \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\}$$
Eq. 1.79

a similar relationship can be derived for $d\mu_A/dX_A$

$$-X_{A}d\mu_{A} = X_{B}d\mu_{B} = RT\left\{1 + \frac{d\ln\gamma_{A}}{d\ln X_{A}}\right\}dX_{B} = RT\left\{1 + \frac{d\ln\gamma_{B}}{d\ln X_{B}}\right\}dX_{B}$$
Eq. 1.80

$$-X_{A}d\mu_{A} = X_{B}d\mu_{B} = X_{A}X_{B}\frac{d^{2}G}{dX^{2}}dX_{B}$$
 Eq. 1.84

The Gibbs-Duhem Equation $\begin{aligned} X_A d\mu_A + X_B d\mu_B &= 0 \\ X_A X_B \frac{d^2 G}{dX^2} &= RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\} \end{aligned}$

be able to calculate the change in chemical potential $(d\mu)$ that result from a change in alloy composition (dX).

Summary II: Binary phase diagrams

- Gibbs Phase Rule F = C - P + 1 (constant pressure)

Gibbs' Phase Rule allows us to construct phase diagram to represent and interpret phase equilibria in heterogeneous geologic systems.

Effect of Temperature on Solid Solubility

 $X_B^e = A \exp\left\{-\frac{Q}{RT}\right\}$ **a)** $T \uparrow \implies X_B^e \uparrow$ **b)** X_B^e can never be equal to zero.

Equilibrium Vacancy Concentration $X_V^e = exp \frac{-\Delta G_V}{RT}$



Influence of Interfaces on Equilibrium

 $\Delta G = \frac{2\gamma W_m}{r}$ Gibbs-Thomson effect

• Gibbs-Duhem Equation: $X_A d\mu_A + X_B d\mu_B = 0$

: Be able to calculate the change in chemical potential that result from a change in alloy composition.

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

합금조성의 미소변화 (dX)로 인한 화학퍼텐셜의 미소변화(dμ) 를 계산